TOSHIBA TC4S66F

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC4S66F

#### **BILATERAL SWITCH**

TC4S66F contains one circuit of bidirectional switches. When control input, CONT is set to "H" level, the impedance between input and output of the switch becomes low and when it is set to "L" level, the switch becomes high. This can be applied for switching of analog signals and digital signals.

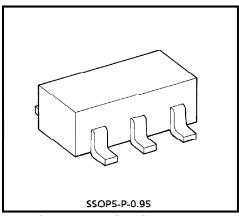
#### **FEATURES**

ON-resistance (R<sub>ON</sub>)

300 $\Omega$  (Typ.) ....  $V_{DD} - V_{SS} = 5V$ 110 $\Omega$  (Typ.) ....  $V_{DD} - V_{SS} = 10V$ 70 $\Omega$  (Typ.) ....  $V_{DD} - V_{SS} = 15V$ 

OFF-resistance (R<sub>OFF</sub>)

R<sub>OFF</sub> (Typ.)  $> 10^9 \Omega$ 



Weight: 0.016g (Typ.)

#### TRUTH TABLE

CONTROL	IMPEDANCE BETWEEN IN/OUT-OUT/IN *
Н	$0.5 \sim 5 \times 10^{2} \Omega$
L	>10°Ω

See static electrical characteristics.

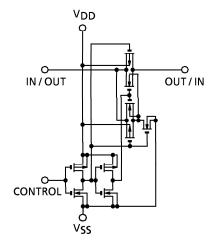
#### **MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
DC Supply Voltage	$V_{DD}$	Vss - 0.5~Vss + 20	V	
Control Input Voltage	V <sub>C</sub> IN	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V	
Switch I/O Voltage	V <sub>I/O</sub>	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	٧	
Power Dissipation	PD	200	mW	
Potential difference across	V. V.	± 0.5	V	
I/O during ON	V <sub>I</sub> -VO	± 0.5		
Control Input Current	IC IN	± 10	mΑ	
Operating Temperature	т	<b>- 40∼85</b>	٥	
Range	T <sub>opr</sub>	-40'-65		
Storage Temperature	T <sub>stg</sub>	<b>-65~150</b>	°C	
Lead Temperature (10s)	TL	260	°C	

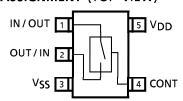
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<sup>●</sup> TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

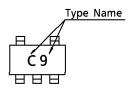
#### **CIRCUIT DIAGRAM**



### PIN ASSIGNMENT (TOP VIEW)



#### **MARKING**



## **RECOMMENDED OPERATING CONDITIONS** $(V_{SS} = 0V)$

CHARACTERISTIC	SYMBOL		MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	$V_{DD}$	_	3	_	18	V
Input/Output Voltage	V <sub>IN</sub> /V <sub>OUT</sub>	_	0	_	$V_{DD}$	V

## STATIC ELECTRICAL CHARACTERISTICS (In case not specifically appointed, $V_{SS} = 0V$ )

CHARACTERISTIC		SYM-	TEST CONDITION	$V_{DD}$	– 40°C		25°C			85°C		UNIT
		BOL		(V)	MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	ONIT
Control In	nut Linh			5	3.5	_	3.5	2.75	_	3.5	_	
Control In	put nigii	$V_{IH}$	$ I_{IS}  = 10 \mu A$	10	7.0	—	7.0	5.50	—	7.0	—	
Voltage				15	11.0	_	11.0	8.25	_	11.0	_	v
Control In	nut low			5	_	1.5	_	2.25	1.5	_	1.5	\ \ \
Voltage	put Low	$V_{IL}$	$ I_{\text{IS}}  = 10 \mu \text{A}$	10	<b> </b>	3.0	_	4.5	3.0	<b> </b>	3.0	
voitage				15	_	4.0	_	6.75	4.0	_	4.0	
		RON	$0 \le V_{IS} \le V_{DD}$ $R_{L} = 10k\Omega$	5	_	800	_	290	950	_	1200	
On-State F	Resistance			10	—	210	<b>—</b>	120	250	—	300	Ω
				15	<b> </b>	140	<b>—</b>	85	160	<b>—</b>	200	
Input/Output Leakage Current			V <sub>IN</sub> = 18V, V <sub>OUT</sub> = 0V	18	_	± 100	_	± 0.1	± 100	_	± 1000	
		lOFF	V <sub>IN</sub> = 0V, V <sub>OUT</sub> = 18V	18	_	± 100	_	± 0.1	± 100	_	± 1000	nA
Quiescent Device Current				5	_	0.25	_	0.001	0.25	_	7.5	
		$I_{DD}$	$V_{IN} = V_{DD}, V_{SS}$	10	_	0.5	<b>—</b>	0.001	0.5	_	15	$\mu$ A
				15	_	1.0	_	0.002	1.0	_	30	
Input	H Level	ļШ	V <sub>IH</sub> = 18V	18	_	0.1	_	10 - 5	0.1	_	1.0	
Current	L Level	lOL	V <sub>IL</sub> = 0V	18	_	- 0.1	_	<b>-</b> 10 <sup>- 5</sup>	- 0.1	_	- 1.0	$\mu$ A

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#### **DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

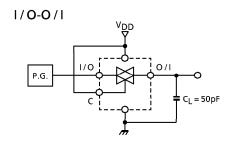
CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>SS</sub> (V)	V <sub>DD</sub> (V)	MIN.	TYP.	MAX.	UNIT
Propagation Delay Time (IN-OUT)	t <sub>pLH</sub> t <sub>pHL</sub>	C <sub>L</sub> = 50pF	0 0 0	5 10 15		15 8 5	40 20 15	
Propagation Delay Time (CONTROL-OUT)	t <sub>pZL</sub> t <sub>pZH</sub>	$R_{L} = 1k\Omega$ $C_{L} = 50pF$	0 0 0	5 10 15		55 25 20	120 40 30	ns
Propagation Delay Time (CONTROL-OUT)	t <sub>pLZ</sub> t <sub>pHZ</sub>	$R_L = 1k\Omega$ $C_L = 50pF$	0 0 0	5 10 15		45 30 25	80 70 60	
Max. Control Input Repetition Rate	fMAX (C)	$R_{L} = 1k\Omega$ $C_{L} = 50pF$	0 0 0	5 10 15		10 12 12		MHz
- 3dB Cut Off Frequency	fMAX (I-O)	$R_L = 1k\Omega$ $C_L = 50pF \qquad (*1)$	- 5	5	_	30	_	
Total Harmonic Distortion	_	$R_L = 10k\Omega$ f = 1kHz (*2)	- 5	5	_	0.03	_	%
– 50dB Feedthrough Frequency		$R_L = 1k\Omega$ (*3)	<b>-</b> 5	5		600	ı	kHz
Crosstalk (CONTROL-OUT)	_	$R_{IN} = 1k\Omega$ $R_{OUT} = 10k\Omega$ $C_L = 15pF$	0 0 0	5 10 15		200 400 600		mV
Input Capacitance	C <sub>IN</sub>	Control Input Switch I/O		•	_	5 10	7.5 —	ъГ
Feedthrough Capacitance	C <sub>IN-OUT</sub>	_			_	0.5	_	pF

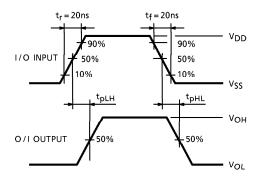
<sup>\*1</sup> The frequency at  $20\ell og_{10}$   $\frac{V_{OS}}{V_{IS}} = -3dB$  shall be  $f_{MAX}(I/O)$  using sine wave of  $\pm 2.5V_{p-p}$  for  $V_{IS}$ .

\*2  $V_{IS}$  shall be sine wave of  $\pm 2.5V$ .

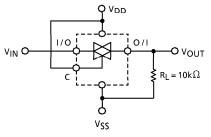
<sup>\*3</sup> The frequency at  $20\ell og_{10} = 50dB$  shall be the feed through using of  $\pm 2.5V_{p-p}$ .

1. t<sub>pLH</sub>, t<sub>pHL</sub>

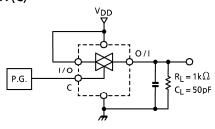




3. RON

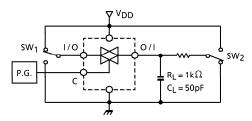


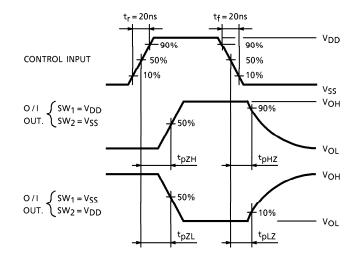
4. fMAX (C)



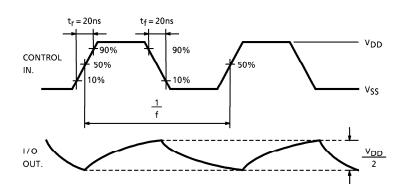
2. tpZL, tpZH, tpLZ, tpHZ

CONTROL-O / I

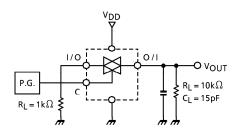


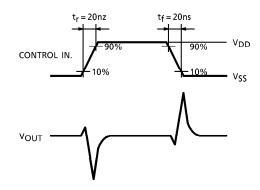


$$R_{\mbox{\scriptsize ON}} = 10 \times \frac{(\mbox{\scriptsize V}_{\mbox{\scriptsize IN}} - \mbox{\scriptsize V}_{\mbox{\scriptsize OUT}})}{\mbox{\scriptsize V}_{\mbox{\scriptsize OUT}}} (\mbox{\scriptsize k}\Omega)$$

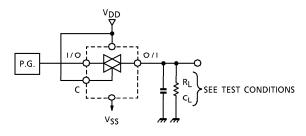


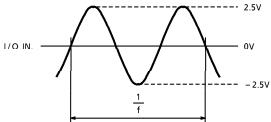
### 5. CROSSTALK (CONTROL INPUT)





## 6. TOTAL HARMONIC DISTORTION, f<sub>MAX</sub> (I/O-O/I), FEEDTHROUGH (SWITCH OFF)

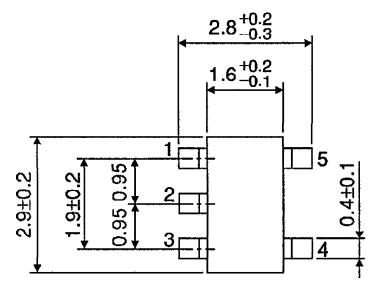


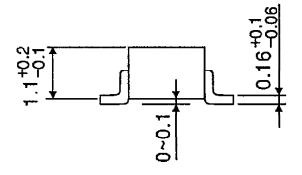


## **OUTLINE DRAWING**

SSOP5-P-0.95

Unit: mm





Weight: 0.016g (Typ.)